

Features

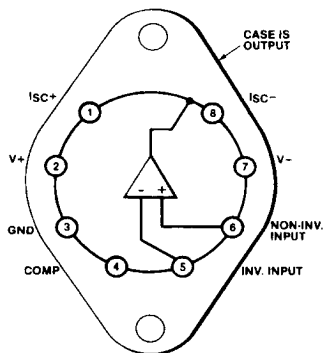
- High output current—1.2A
- Large output voltage swing— $\pm 12V$
- Low standby power—100 mW
- Wide full power bandwidth—20 kHz
- Low input bias current
- Low input offset voltage
- High open-loop gain > 100 dB
- MIL-STD-883 devices 100% manufactured in U.S.A.

Ordering Information

Part No.	Temp. Range	Pkg.	Outline #
ELH0021K/883B	-55°C to $+125^{\circ}\text{C}$	TO-3	MDP0003

8508801YX is the SMD version of this device.

Connection Diagram



Top View

0021-1

General Description

The ELH0021 is a general purpose operational amplifier capable of delivering large output currents not usually associated with conventional IC op amps; the ELH0021 will provide output currents in excess of 1A at voltage levels of $\pm 12V$. In addition, both the inputs and outputs are protected against overload. The device is compensated with a single external capacitor and are free of any unusual oscillation or latch-up problems.

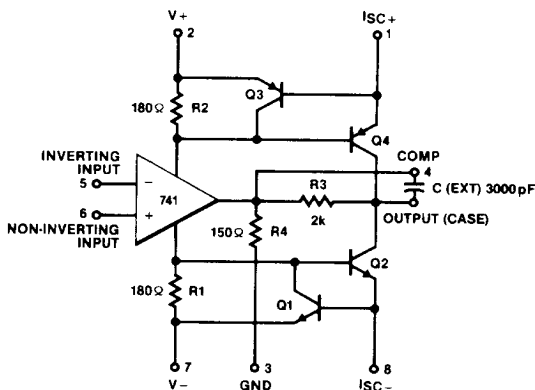
The excellent input characteristics and high output capability of the ELH0021 make it an ideal choice for power applications such as DC servos, capstan drivers, deflection yoke drivers, and programmable power supplies.

Other applications include torque drivers for inertial guidance systems, diddle yoke drivers for alphanumeric CRT displays, cable drivers, and programmable power supplies for automatic test equipment.

The ELH0021 is supplied in an 8-pin TO-3 package rated at 20W with suitable heatsink. The ELH0021 is guaranteed over the temperature range of -55°C to $+125^{\circ}\text{C}$.

Elantec facilities comply with MIL-I-45208A and other applicable quality specifications. Elantec's Military devices are 100% fabricated and assembled in our rigidly controlled, ultra-clean facilities in Milpitas, California. For additional information on Elantec's Quality and Reliability Assurance policy and procedures request brochure QRA-1.

Equivalent Schematic



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ELH0021K/883/8508801YX

1 Amp Power Operational Amplifier

ELH0021K/883/8508801YX

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

V_S	Supply Voltage	$\pm 18\text{V}$	T_A	Operating Temperature Range	
V_{IN}	Input Voltage (Note 1)	$\pm 15\text{V}$		ELH0021	-55°C to $+125^\circ\text{C}$
P_D	Power Dissipation (See Curves)		T_{ST}	Storage Temperature	-65°C to $+150^\circ\text{C}$
	Differential Input Voltage	$\pm 30\text{V}$		Lead Temperature	
	Peak Output Current (Note 2)	2A		(Soldering, 10 seconds)	300°C
	Output Short				
	Circuit Duration (Note 3)	Continuous			

Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ\text{C}$ and QA sample tested at $T_A = 25^\circ\text{C}$, T_{MAX} and T_{MIN} per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ\text{C}$ for information purposes only.

DC Electrical Characteristics $V_S = \pm 15\text{V}$, $T_{MIN} \leq T_A \leq T_{MAX}$, $C_C = 3000\text{ pF}$

Parameter	Description	Test Conditions	ELH0021				Units
			Min	Typ	Max	Test Level	
V_{OS}	Input Offset Voltage	$R_S \leq 100\Omega$, $T_C = 25^\circ\text{C}$ (Note 4)		1	3	I	mV
		$R_S \leq 100\Omega$ (Note 4)			5	I	mV
$\Delta V_{OS}/\Delta T$	Voltage Drift with Temperature	$R_S \leq 100\Omega$		3	25	IV	$\mu\text{V}/^\circ\text{C}$
	Offset Voltage Drift with Time	$T_A = 25^\circ\text{C}$		5		V	$\mu\text{V}/\sqrt{\text{wk}}$
$\Delta V_{OS}/\Delta P$	Offset Voltage Change with Output Power			5	15	I	$\mu\text{V}/\text{W}$
I_{OS}	Input Offset Current	$T_C = 25^\circ\text{C}$ (Note 4)		30	100	I	nA
		(Note 4)			300	I	nA
	Offset Current Drift with Temperature			0.1	1	IV	$\text{nA}/^\circ\text{C}$
	Offset Current Drift with Time	$T_A = 25^\circ\text{C}$		2		V	$\text{nA}/\sqrt{\text{wk}}$
I_B	Input Bias Current	$T_C = 25^\circ\text{C}$ (Note 4)		100	300	I	nA
		(Note 4)			1	I	μA
R_{IN}	Input Resistance	$T_C = 25^\circ\text{C}$	0.3	1		I	$\text{M}\Omega$
CMRR	Common-Mode Rejection Ratio	$R_S \leq 100\Omega$, $V_{CM} = \pm 10\text{V}$	70	90		I	dB
V_{INCM}	Input Voltage Range		± 12			IV	V

ELH0021K/883/8508801YX**1 Amp Power Operational Amplifier****DC Electrical Characteristics** $V_S = \pm 15V$, $T_{MIN} \leq T_A \leq T_{MAX}$, $C_C = 3000 \text{ pF}$ — Contd.

Parameter	Description	Test Conditions	ELH0021				Units
			Min	Typ	Max	Test Level	
PSRR	Power Supply Rejection Ratio	$R_S \leq 100\Omega$, $V_S = \pm 5V$ to $\pm 15V$	80	96		I	dB
A _{VOL}	Voltage Gain (Note 5)	$V_O = \pm 10V$, $R_L = 1 \text{ k}\Omega$, $T_C = 25^\circ\text{C}$	100	200		I	V/mV
		$V_O = \pm 10V$, $R_L = 100\Omega$	25			I	V/mV
V _O	Output Voltage Swing	$R_L = 100\Omega$	± 13.5	14		I	V
		$R_L = 10\Omega$, $T_C = 25^\circ\text{C}$	± 11	± 12		I	V
I _{SC}	Output Short Circuit Current	$T_C = 25^\circ\text{C}$, $R_{SC} = 0.5\Omega$	0.8	1.2	1.6	I	A
I _S	Supply Current	$V_{OUT} = 0V$		2.5	3.5	I	mA
P _C	Power Consumption	$V_{OUT} = 0V$		75	105	I	mW

Note 1: Rating applies for supply voltages above $\pm 15V$. For supplies less than $\pm 15V$, rating is equal to supply voltage.

Note 2: Rating applies for ELH0021K with $R_{SC} = 0\Omega$.

Note 3: Rating applies as long as package power rating is not exceeded.

Note 4: Specifications apply for $\pm 5V \leq V_S \leq \pm 18V$.

Note 5: The ELH0021, like all Class B amplifiers, has a "dead band" when V_{OUT} is near 0V. Typical values for the "dead band" are in the $50 \mu\text{V}$ to $200 \mu\text{V}$ range. Open-loop gain is measured at V_{OUT} from $\pm 0.5 V_{DC}$ TO $\pm 10.0 V_{DC}$ which is out of the range of the "dead band".

AC Electrical Characteristics $T_A = 25^\circ\text{C}$, $V_S = \pm 15V$, $C_C = 3000 \text{ pF}$

Parameter	Description	Test Conditions	ELH0021				Units
			Min	Typ	Max	Test Level	
SR	Slew Rate	$A_V = 1$, $R_L = 100\Omega$	1.5	3		I	V/ μs
BW	Bandwidth	$R_L = 100\Omega$		20		V	kHz
t_r , t_f	Small Signal Rise or Fall Time			0.3	1	I	μs
	Small Signal Overshoot			5	20	I	%
t_S	Settling Time (0.1%)	$\Delta V_{IN} = 10V$, $A_V = 1$		4		V	μs
	Overload Recovery Time			3		V	μs
HD	Harmonic Distortion	$f = 1 \text{ kHz}$, $P_O = 0.5W$		0.2		V	%
e_n	Input Noise Voltage	$R_S = 50\Omega$, BW = 10 Hz to 10 kHz		5		V	μVrms
i_n	Input Noise Current	BW = 10 Hz to 10 kHz		0.05		V	nA _{rms}
C _{IN}	Input Capacitance			3		V	pF

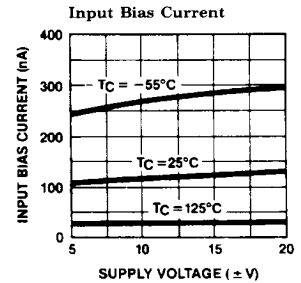
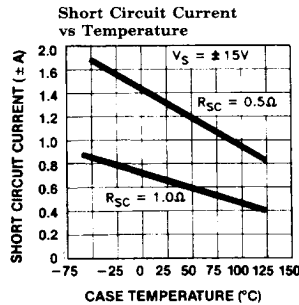
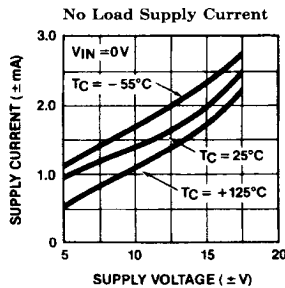
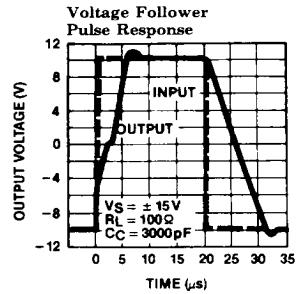
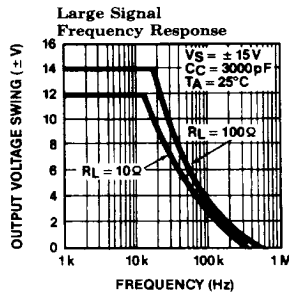
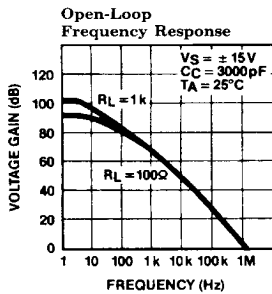
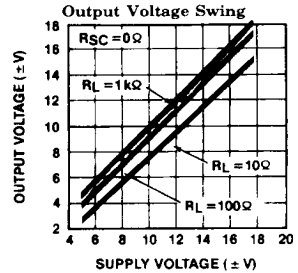
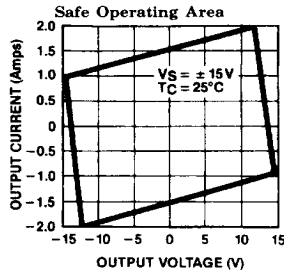
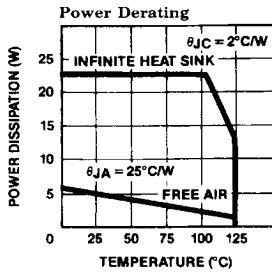
ELH0021K/883/8508801YX

1 Amp Power Operational Amplifier

ELH0021K/883/8508801YX

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Typical Performance Curves

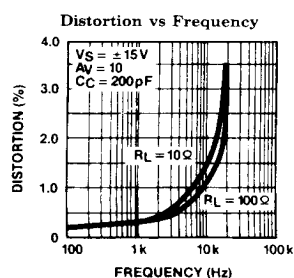
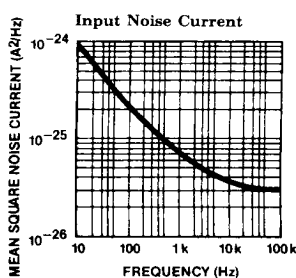
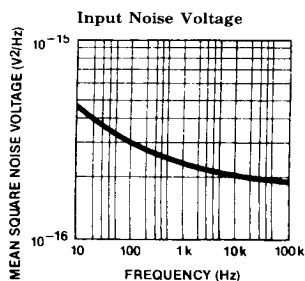
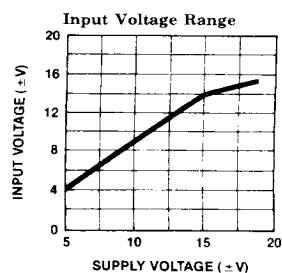
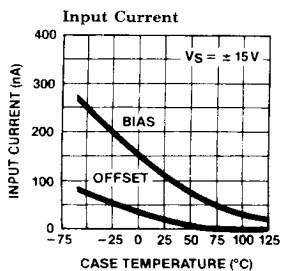
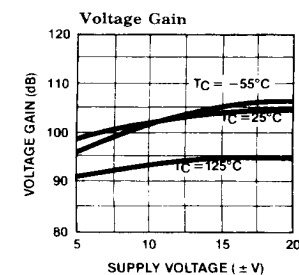


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ELH0021K/883/8508801YX

1 Amp Power Operational Amplifier

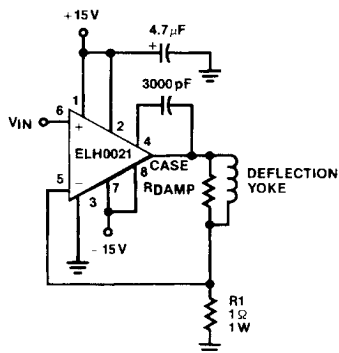
Typical Performance Curves — Contd.



0021-4

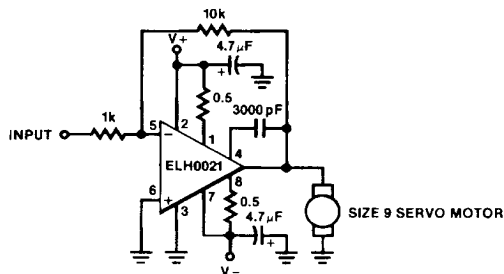
Typical Applications

CRT Deflection Yoke Driver



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DC Servo Amplifier



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ELH0021K/883/8508801YX

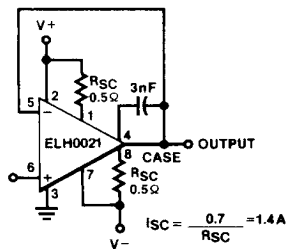
1 Amp Power Operational Amplifier

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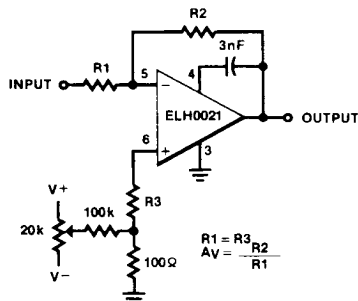
Typical Applications — Contd.

Unity Gain with Short Circuit Limiting



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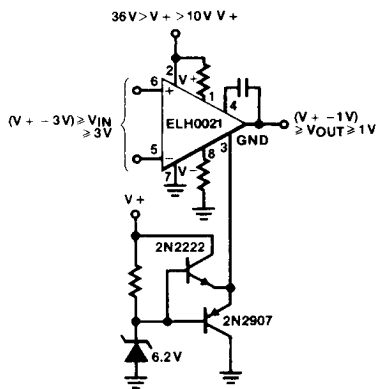
Offset Voltage Null Circuit



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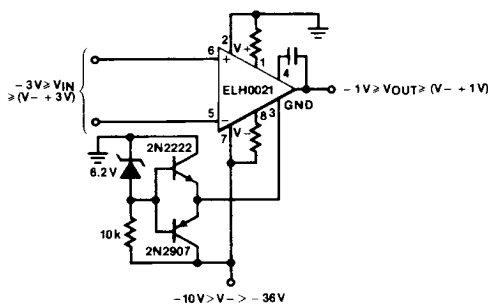
Operation from Single Supplies

Positive



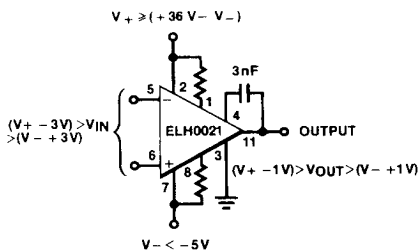
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Negative

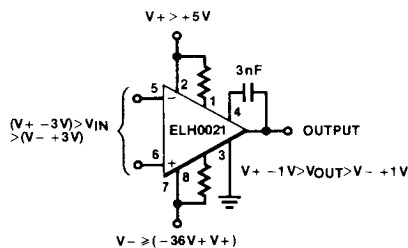


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Operation from Non-Symmetrical Supplies



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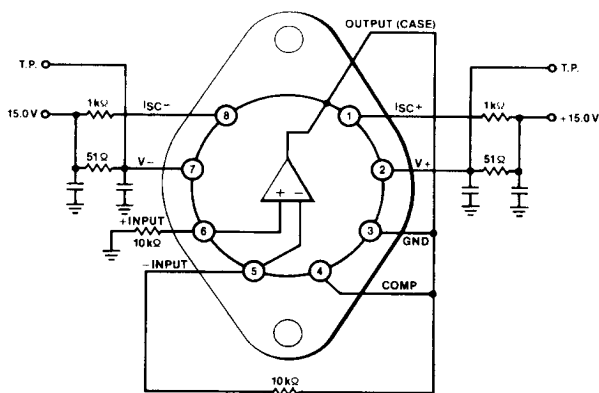


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ELH0021K/883/8508801YX

1 Amp Power Operational Amplifier

Burn-In Circuit



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